

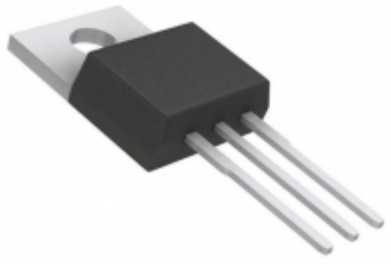








	<h2 style="color: red;">FQP8N80C</h2> <p>Hersteller-Teilenummer: FQP8N80C</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 800V 8A TO-220</p> <p>Datenblätter:  1.FQP8N80C.pdf  2.FQP8N80C.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 36869 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
 <p style="font-size: small;">YIC International Co., Limited.</p>	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP8N80C
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 800V 8A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	36869 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	178W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	800V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	8A (Tc)
Rds On (Max) @ Id, Vgs	1.55 Ohm @ 4A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	45nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2050pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube



















































FQP8N80C ist neu im Original, Suche FQP8N80C Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP8N80C Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FQP8N80C: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP8P10 AMI Semiconductor / ON Semiconductor MOSFET P-CH 100V 8A TO-220</p>	 <p>FQP8N80 Fairchild/ON Semiconductor FQP8N80 FAIRCHILD</p>	 <p>FQP8P10 Fairchild/ON Semiconductor MOSFET P-CH 100V 8A TO-220</p>	 <p>FQP8N90 FSC FQP8N90 FSC</p>
 <p>FQP8N60C AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 7.5A TO-220</p>	 <p>FQP8N90C Fairchild/ON Semiconductor MOSFET N-CH 900V 6.3A TO-220</p>	 <p>FQP8N90C AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 6.3A TO-220</p>	 <p>FQP8N60CFT FAIRCHILD FAIRCHILD TO-220F</p>

heiße Teile

Mehr

 FQP6N90C	 FQP6N90C	 FQP70N03L	 FQP70N06	 FQP70N06C
 FQP70N08	 FQP70N08	 FQP70N10	 FQP70N10	 FQP7N10L
 FQP7N10L	 FQP7N20L	 FQP7N20L	 FQP7N60C	 FQP7N65C
 FQP7N65C	 FQP7N80C	 FQP7N80C	 FQP85N06	 FQP85N06
 FQP8N50C	 FQP8N60C	 FQP8N60C	 FQP8N65C	 FQP8N80C
 FQP8N90C	 FQP8N90C	 FQP90N08	 FQP90N08	 FQP90N10V2
 FQP90N10V2	 FQP9N08L	 FQP9N08L	 FQP9N25C	 FQP9N25C
 FQP9N50C	 FQP9N50C	 FQP9N65C	 FQP9N90C	 FQP9N90C
 FQPF10N20	 FQPF10N20	 FQPF10N20C	 FQPF10N20C	 FQPF10N50CF
 FQPF10N50CF	 FQPF10N60	 FQPF10N60C	 FQPF10N60C	 FQPF10N60CF

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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